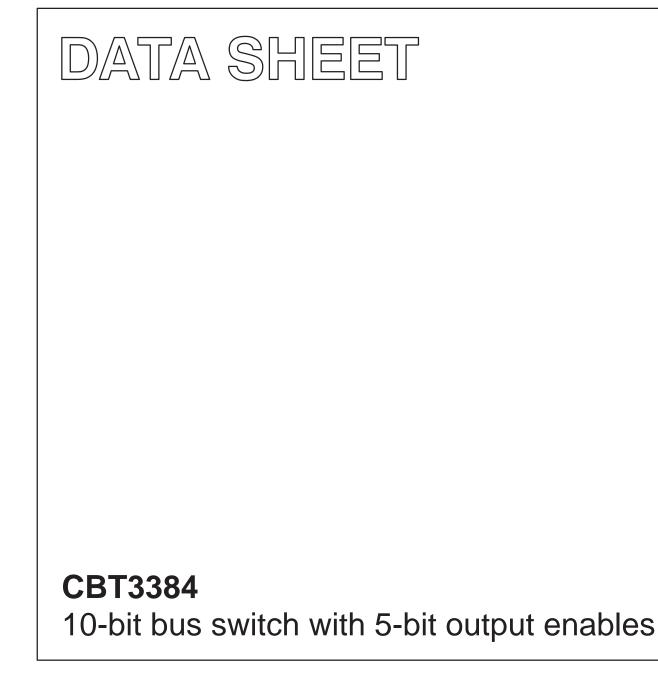
# INTEGRATED CIRCUITS



Product data Supersedes data of 2001 Mar 10 File under Integrated Circuits — ICL03

2001 Dec 20



HILIP

### **CBT3384**

#### **FEATURES**

- 5 Ω switch connection between two ports
- TTL compatible control input and output levels
- See CBTS3384 for CBT3384 with Schottky diode undershoot protection
- See CBTD3384 for CBT3384 with level shifting diodes
- Latch-up is done to JESDEC Standard JESD78 which exceeds 100 mA
- ESD classification testing is done to JESDEC Standard JESD22. Protection exceeds 2000 V to HBM per method A114 and 1000 V CDM per method C101.

#### DESCRIPTION

The CBT3384 provides ten bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The CBT3384 device is organized as two 5-bit bus switches with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is LOW, the switch is on and port A is connected to B. When  $\overline{OE}$  is HIGH, the switch is open and high-impedance state exists between the two ports.

The CBT3384 is characterized for operation from -40 to +85 °C.

| 10E 1  | 24 Vcc             |     |
|--------|--------------------|-----|
| 1B1 2  | 23 2B5             |     |
| 1A1 3  | 22 2A5             |     |
| 1A2 4  | 21 2A4             |     |
| 1B2 5  | 20 2B4             |     |
| 1B3 6  | 19 2B3             |     |
| 1A3 7  | 18 2A3             |     |
| 1A4 8  | 17 2A2             |     |
| 1B4 9  | 16 2B2             |     |
| 1B5 10 | 15 2B1             |     |
| 1A5 11 | 14 2A1             |     |
| GND 12 | 13 2 <del>0E</del> |     |
|        |                    |     |
|        | SA                 | 004 |

#### **PIN DESCRIPTION**

| PIN NUMBER         | SYMBOL                    | NAME AND FUNCTION       |
|--------------------|---------------------------|-------------------------|
| 1, 13              | 1 <u>0E</u> , 2 <u>0E</u> | Output enables          |
| 3, 4, 7, 8, 11     | 1A1–1A5                   | Inputs                  |
| 14, 17, 18, 21, 22 | 2A1–2A5                   | Inputs                  |
| 2, 5, 6, 9, 10     | 1B1–1B5                   | Outputs                 |
| 15, 16, 19, 20, 23 | 2B1–2B5                   | Outputs                 |
| 12                 | GND                       | Ground (0 V)            |
| 24                 | V <sub>CC</sub>           | Positive supply voltage |

#### QUICK REFERENCE DATA

| SYMBOL                               | PARAMETER                     | PARAMETER CONDITIONS<br>T <sub>amb</sub> = 25 °C; GND = 0 V |     | UNIT |
|--------------------------------------|-------------------------------|---|-----|------|
| t <sub>PLH</sub><br>t <sub>PHL</sub> | Propagation delay<br>An to Yn | $C_{L} = 50 \text{ pF}; V_{CC} = 5 \text{ V}$               | 250 | ps   |
| C <sub>IN</sub>                      | Input capacitance             | $V_I = 0 V \text{ or } V_{CC}$                              | 4   | pF   |
| C <sub>OUT</sub>                     | Output capacitance            | Outputs disabled; $V_0 = 0 V$ or $V_{CC}$                   | 10  | pF   |
| I <sub>CCZ</sub>                     | Total supply current          | Outputs disabled; $V_{CC} = 5.5 V$                          | 3   | μΑ   |

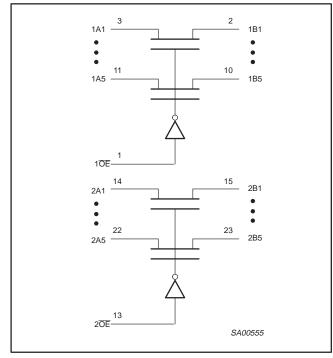
#### **ORDERING INFORMATION**

| PACKAGES                   | TEMPERATURE RANGE | ORDER CODE | DWG NUMBER |
|----------------------------|-------------------|------------|------------|
| 24-Pin Plastic SO          | −40 to +85 °C     | CBT3384D   | SOT137-1   |
| 24-Pin Plastic SSOP        | −40 to +85 °C     | CBT3384DB  | SOT340-1   |
| 24-Pin Plastic SSOP (QSOP) | −40 to +85°C      | CBT3384DK  | SOT556-1   |
| 24-Pin Plastic TSSOP       | −40 to +85 °C     | CBT3384PW  | SOT355-1   |

Standard packing quantities and other packaging data is available at www.philipslogic.com/packaging.

### CBT3384

#### LOGIC SYMBOL



#### **FUNCTION TABLE**

| INP             | JTS               | OUTF    | PUTS    |
|-----------------|-------------------|---------|---------|
| 1 <del>0E</del> | 2 <mark>0E</mark> | 1A, 1B  | 2A, 2B  |
| L               | L                 | 1A = 1B | 2A= 2B  |
| L               | Н                 | 1A = 1B | Z       |
| н               | L                 | Z       | 2A = 2B |
| н               | Н                 | Z       | Z       |

H = High voltage level

L = Low voltage level

Z = High impedance "off" state

#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

| SYMBOL           | PARAMETER                     | PARAMETER CONDITIONS |              | UNIT |
|------------------|-------------------------------|----------------------|--------------|------|
| V <sub>CC</sub>  | DC supply voltage             |                      | -0.5 to +7.0 | V    |
| I <sub>IK</sub>  | DC input diode current        |                      | -50          | mA   |
| VI               | DC input voltage <sup>3</sup> |                      | -1.2 to +7.0 | V    |
| I <sub>SW</sub>  | DC output diode current       | V <sub>O</sub> < 0   | ±128         | mA   |
| T <sub>stg</sub> | Storage temperature range     |                      | -65 to +150  | °C   |

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

| SYMBOL           | PARAMETER                            | LIM | ITS | UNIT |
|------------------|--------------------------------------|-----|-----|------|
| STMBOL           | PARAMETER                            | Min | Max | UNIT |
| V <sub>CC</sub>  | DC supply voltage                    | 4.5 | 5.5 | V    |
| V <sub>IH</sub>  | High-level input voltage             | 2.0 | _   | V    |
| V <sub>IL</sub>  | Low-level Input voltage              | —   | 0.8 | V    |
| T <sub>amb</sub> | Operating free-air temperature range | -40 | +85 | °C   |

# **CBT3384**

#### DC ELECTRICAL CHARACTERISTICS

| SYMBOL PARAMETER             |  | TEST CONDITIONS   | T <sub>amb</sub> = |                  |      |    |
|------------------------------|--|---|--------------------|------------------|------|----|
|                              |  |   | Min                | Typ <sup>1</sup> | Max  | 1  |
| V <sub>IK</sub>              | Input clamp voltage                                  | $V_{CC} = 4.5 \text{ V}; \text{ I}_{\text{I}} = -18 \text{ mA}$                                     | —                  | —                | -1.2 | V  |
| Ιį                           | Input leakage current                                | $V_{CC}$ = 5.5 V; V <sub>I</sub> = GND or 5.5 V   | —                  | —                | ±1   | μΑ |
| I <sub>CC</sub>              | Quiescent supply current <sup>2</sup>                | $V_{CC}$ = 5.5 V; $I_O$ = 0, $V_I$ = $V_{CC}$ or GND  | —                  | —                | 3    | μΑ |
| $\Delta I_{CC}$              | Additional supply current per input pin <sup>2</sup> | $V_{CC}$ = 5.5 V, one input at 3.4 V, other inputs at $V_{CC}$ or GND                               | —                  | —                | 2.5  | mA |
| Cl                           | Control pins   | V <sub>1</sub> = 3.0 V or 0   | —                  | 4                | —    | pF |
| C <sub>I(OFF)</sub>          | Port off capacitance                                 | $V_{O} = 3.0 \text{ V or } 0, \overline{OE} = V_{CC}$   | —                  | 10               | —    | pF |
|                              |  | $V_{CC} = 4.5 \text{ V}; V_{I} = 0 \text{ V}; I_{I} = 64 \text{ mA}$                                | —                  | 5                | 7    |    |
| r <sub>on</sub> <sup>3</sup> | On-resistance  | $V_{CC} = 4.5 \text{ V}; V_{I} = 0 \text{ V}; I_{I} = 30 \text{ mA}$                                | —                  | 5                | 7    | Ω  |
|                              |  | $V_{CC} = 4.5 \text{ V}; V_I = 2.4 \text{ V}; I_I = -15 \text{ mA}$                                 | —                  | 10               | 15   |    |
| VP                           | Pass voltage   | $V_{I} = V_{CC} = 5.0 \text{ V}; I_{O} = -100 \mu\text{A}$  | 3.4                | 3.6              | 3.9  | V  |
| I <sub>UCP</sub>             | Undershoot static current protection                 | $V_{CC}$ = 5.0 V, I <sub>B</sub> = 400 $\mu$ A; $\overline{OE}$ = 5.0 V; V <sub>B</sub> $\ge$ 3.0 V | _                  | 8                | —    | mA |

NOTES:

1. All typical values are at V<sub>CC</sub> = 5 V,  $T_{amb}$  = 25 °C

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND. 2.

3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

#### **AC CHARACTERISTICS**

 $GND = 0 V; t_{R}; C_{L} = 50 pF$ 

|                  |  |                 |                | LIM                    |            |      |
|------------------|--|-----------------|----------------|------------------------|------------|------|
| SYMBOL           | PARAMETER                                      | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = +5.0 | 0 V ±0.5 V | UNIT |
|                  |  | (               | (000000)       | Min                    | Мах        |      |
| t <sub>pd</sub>  | Propagation delay <sup>1</sup>                 | A or B          | B or A         | _                      | .25        | ns   |
| t <sub>en</sub>  | Output enable time<br>to High and Low level    | ŌĒ              | A or B         | 1.0                    | 5.7        | ns   |
| t <sub>dis</sub> | Output disable time<br>from High and Low level | ŌĒ              | A or B         | 1.0                    | 5.2        | ns   |

NOTE:

1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

|                  |                                    |      | LIMITS  |         |    |
|------------------|------------------------------------|------|---|---------|----|
| SYMBOL           | PARAMETER DESCRIPTION              | т    | <sub>amb =</sub> −40 to +85 <sup>°</sup><br>V <sub>CC</sub> = 5 V, ±0.5 V | °C<br>/ |    |
|                  |                                    | MIN. | MEAN  | MAX.    | 1  |
| t <sub>pd</sub>  | Propagation delay (see Note 1)     | —    | —   | 250     | ps |
| t <sub>PZH</sub> | Output enable time to High level   | 1.6  | 3.4   | 5.6     | ns |
| t <sub>PHZ</sub> | Output enable time from High level | 1.7  | 3.3   | 5.5     | ns |
| t <sub>PZL</sub> | Output enable time to Low level    | 2.3  | 4   | 6       | ns |
| t <sub>PLZ</sub> | Output enable time from Low level  | 2.5  | 4.5   | 6.6     | ns |

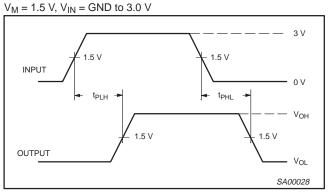
NOTE:

1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance); at +25 °C.

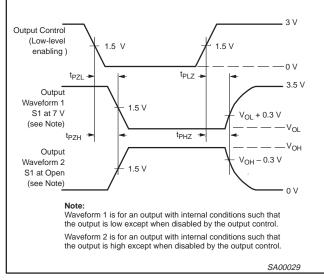
Product data

# CBT3384

#### AC WAVEFORMS

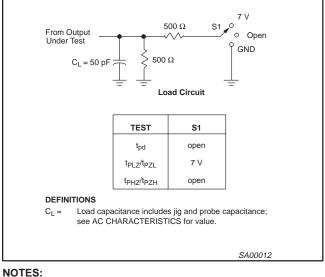


#### Waveform 1. Input (An) to Output (Yn) Propagation Delays



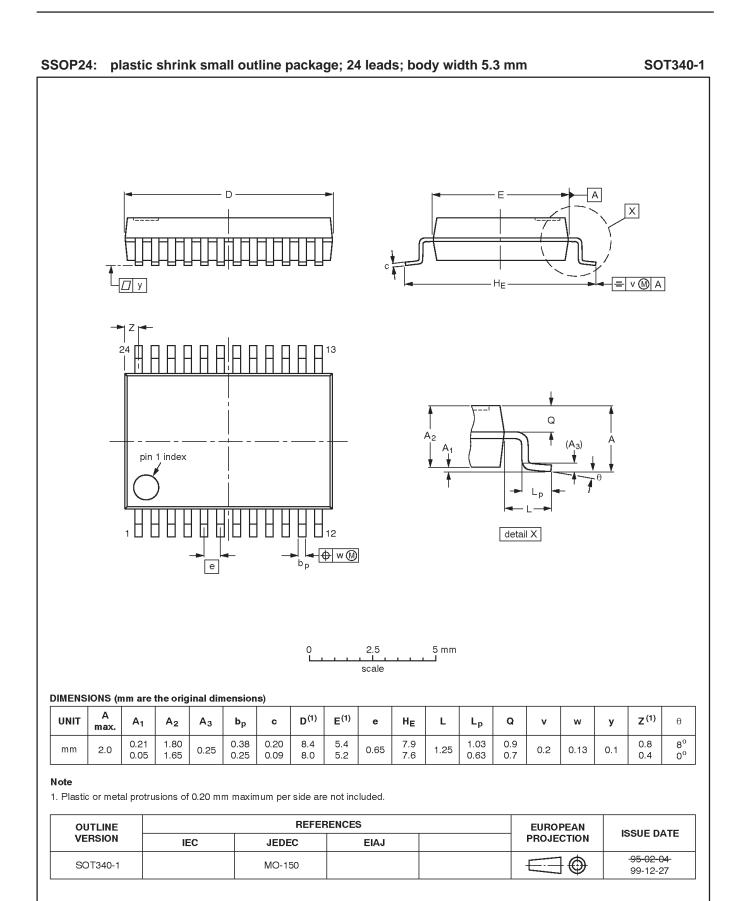
Waveform 2. 3-State Output Enable and Disable Times

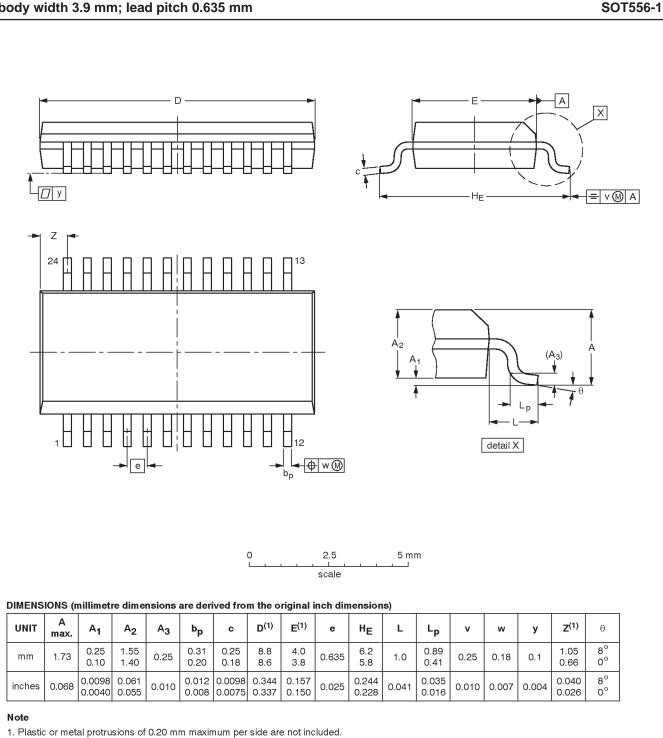
#### **TEST CIRCUIT AND WAVEFORMS**



- 1. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- 2. The outputs are measured one at a time with one transition per measurement.

SO24: plastic small outline package; 24 leads; body width 7.5 mm SOT137-1 D Α Х  $H_{\rm F}$ = v 🕅 A  $\overline{\Pi}$ у 13 Q 4 ٩0  $(A_3)$ A. pin 1 index 12 detail X ↓<mark>↓</mark> bp е 10 mm 0 5 scale DIMENSIONS (inch dimensions are derived from the original mm dimensions) Α z<sup>(1)</sup> D <sup>(1)</sup> E<sup>(1)</sup> UNIT Α1 A<sub>2</sub> Α3  $\mathsf{H}_\mathsf{E}$ Lp Q θ bp с L v w У е max. 0.30 2.45 0.49 0.32 15.6 7.6 10.65 1.1 1.1 0.9 2.65 0.1 mm 0.25 1.27 1.4 0.25 0.25 0.10 2.25 0.36 0.23 15.2 7.4 10.00 0.4 1.0 0.4 8<sup>0</sup>  $0^{\mathrm{o}}$ 0.30 0.043 0.035 0.012 0.096 0.019 0.013 0.61 0.419 0.043 inches 0.10 0.050 0.055 0.004 0.01 0.01 0.01 0.004 0.089 0.014 0.009 0.60 0.29 0.394 0.016 0.039 0.016 Note 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included. REFERENCES OUTLINE EUROPEAN **ISSUE DATE** PROJECTION VERSION IEC JEDEC EIAJ 97-05-22 SOT137-1 075E05 MS-013  $\odot$ £ 99-12-27

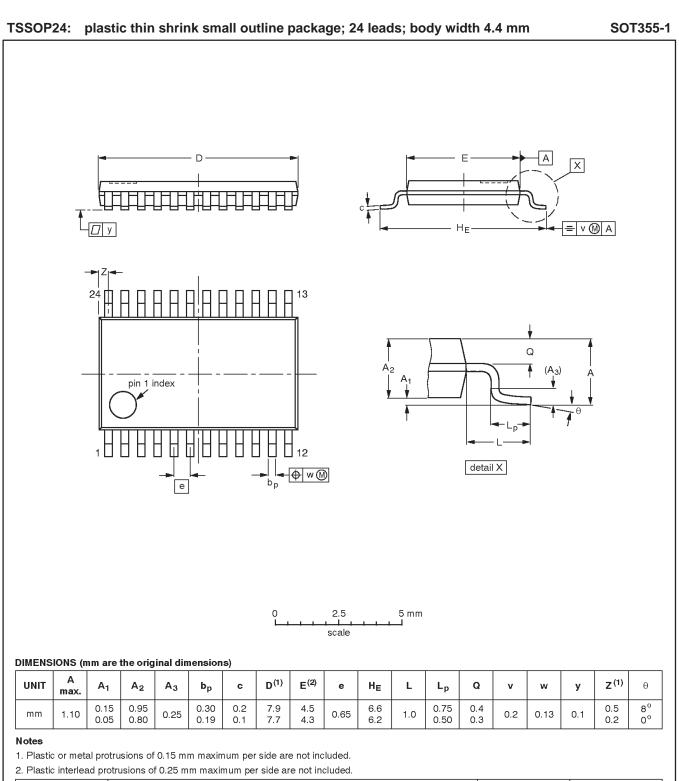




# SSOP24: plastic shrink small outline package; 24 leads; body width 3.9 mm; lead pitch 0.635 mm

| OUTLINE  |     | REFERENCES |      |  | EUROPEAN ISSUE DATE |                                   |
|----------|-----|------------|------|--|---------------------|-----------------------------------|
| VERSION  | IEC | JEDEC      | EIAJ |  | PROJECTION          | 1550E DATE                        |
| SOT556-1 |     | MO-137     |      |  |                     | <del>-99-05-05-</del><br>99-12-27 |
|          |     |            |      |  |                     |                                   |

#### \_\_\_\_\_



# CBT3384

#### Data sheet status

| Data sheet status <sup>[1]</sup> | Product<br>status <sup>[2]</sup> | Definitions  |
|----------------------------------|----------------------------------|--|
| Objective data                   | Development                      | This data sheet contains data from the objective specification for product development.<br>Philips Semiconductors reserves the right to change the specification in any manner without notice.   |
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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